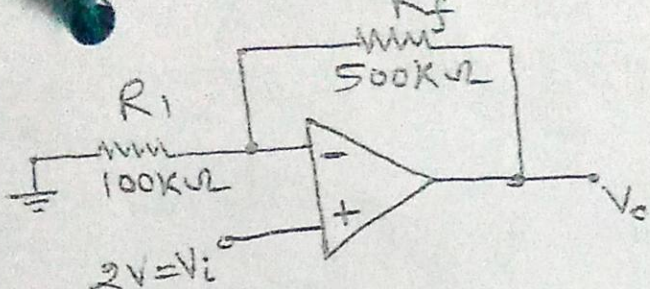
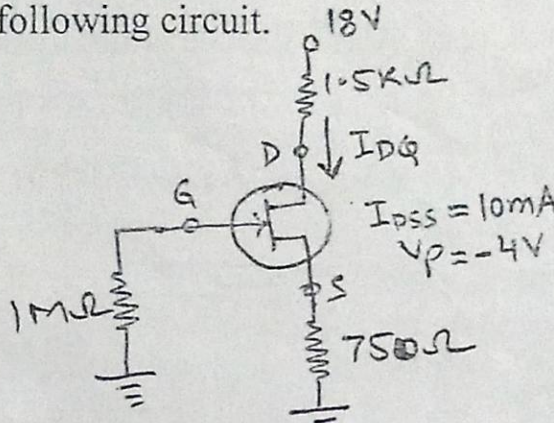
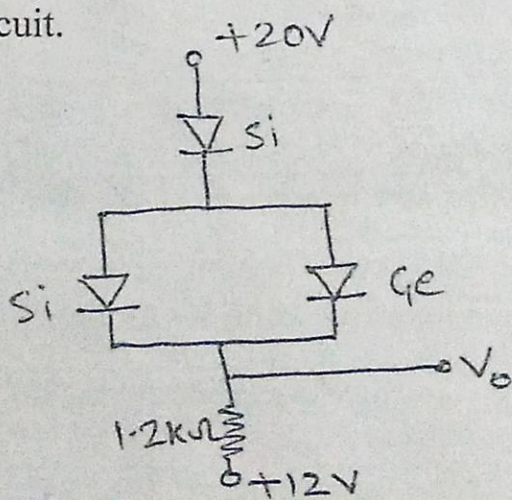


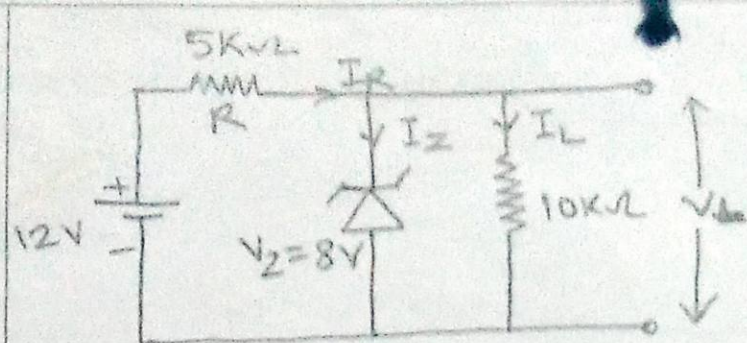
School of Engineering
Second Sessional Examination, Even Semester (AS: 2022-23)
B. Tech: CS-10, CS-19, AI-1(CSE), AI-2(CSE), AI-3(CSE), CCML-1(CSE), IOTBC-1(CSE)
Year: 1st Semester: 2nd

Course Title: Basic Electronics Engineering **Max Marks: 60**
Course Code: BEC3201 **Time: 3hrs**

Instructions: Read the question Carefully.

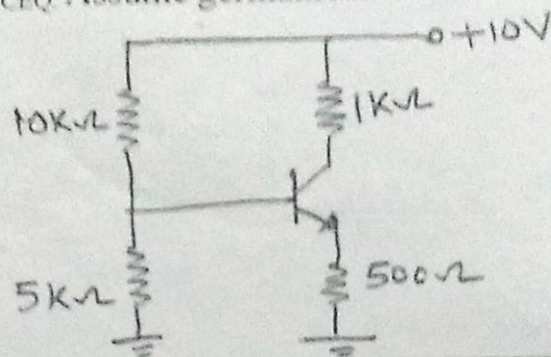
SECTION 'A'		Course Objective	Marks
Q.N.1. Attempt all parts of the following:			
a)	What is the PIV of the diode used in Half wave rectifier?	CO1	1
b)	Draw the characteristics of ideal diode.	CO1	1
c)	What do you mean by I_{CBO} ?	CO1	1
d)	Why gate current is always zero in MOSFET?	CO2	1
e)	Implement X-OR gate with basic gate?	CO3	1
f)	Define amplitude modulation	CO3	1
g)	What do you mean by CMRR?	CO2	1
h)	Draw the circuit diagram of differentiator and Integrator.	CO2	1
SECTION 'B'		Course Objective	Marks
Q.N.2. Attempt any two parts of the following:			
a)	Explain working of full wave Bridge rectifier with input and output waveforms. In a centre tap full wave rectifier the rms half secondary voltage is 9 V. Assume load resistor (R_L) of 1 K Ω and diode forward resistor of 1 Ω . Calculate I_{dc} , I_{rms} , ripple factor, P_{dc} , P_{ac} and rectification efficiency.	CO1	6
b)	Perform the following conversion. (i) $(64.625)_{10} = (?)_2$ (ii) $(47.32)_8 = (?)_{10}$ (iii) $(EF8C.D06)_{16} = (?)_2$ (iv) $(235.151)_8 = (?)_{16}$	CO3	6
c)	Derive the expression for the output of difference amplifier using OP-Amp. Find the output voltage of the following circuit		6

		CO2	
d)	<p>Explain the working of n-channel JFET. Also define JFET parameters. Determine I_{DSQ} and V_{DSQ} for the following circuit.</p> 	CO2	6
SECTION 'C'		Course Objective	Marks
Q.N.3. Attempt any two parts of the following:			
a)	<p>Explain the working of pn junction diode in reverse bias condition. Determine V_o for the following circuit.</p> 	CO1	5
b)	<p>What do you mean by breakdown? Explain Zener breakdown mechanism. For the following circuit find V_L, I_L, I_Z, and I_R.</p>		5



CO1

c) For the following voltage divider Circuit find I_{CQ} and V_{CEQ} . Assume germanium transistor and $\beta = 100$.



CO1

5

Q.N.4. Attempt any two parts of the following:

- With neat sketch explain the working of PNP transistor. Also derive the relationship between α and β .
- Explain the input and output characteristics of a BJT in CB configuration.
- Explain the construction and drain characteristics of N channel D-MOSFET.

CO2

5

CO2

5

CO2

5

Q.N.5. Attempt any two parts of the following:

- Explain the block diagram of Communication system. What is the need for modulation?
- Perform the following subtraction using 1's and 2's complement
 $(24)_{10} - (17)_{10}$
- What are the universal gates?
Reduce the following function using k map and implement the reduced function with NAND gate

CO3

5

CO3

5

CO3

5

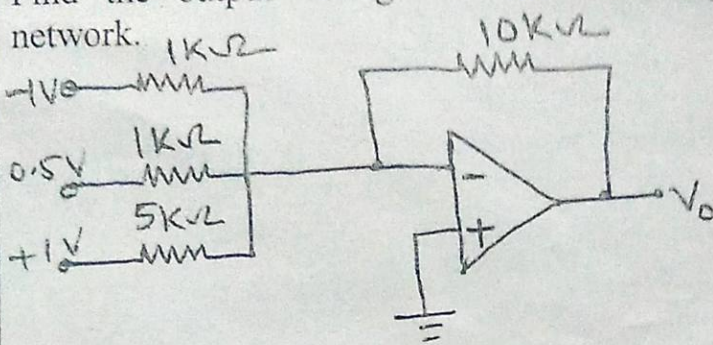
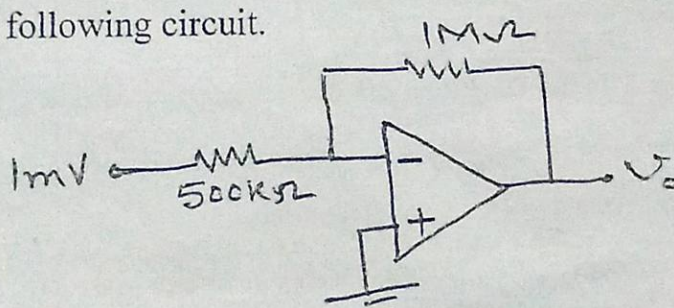
$F(A, B, C, D) = \Sigma(0, 1, 4, 5, 6, 7, 8, 9, 10, 11, 13, 14)$				
Q.N.6. Attempt any two parts of the following:				
a)	<p>Derive the output expression for the inverting summing op amp. Find the output voltage for the following network.</p> 	CO2	5	
b)	<p>Enlist the characteristics of ideal op-amp. Derive the expression of the output of the non-inverting op amp. Find the output V_o of the following circuit.</p> 	CO3	5	
c)	<p>Which type of feedback is used for the oscillation? Explain the principle of oscillator and describe the Barkhausen Criterion.</p>	CO3	5	

Table 1: Mapping between COs and questions

(Number of COs may vary from course to course)

COs	Questions Numbers	Total Marks
CO1	Q1(a,b,c)Q2(a)Q3(a,b,c)	24
CO2	Q1(d,g,h)Q2(c,d)Q4(a,b,c)Q6(a)	35
CO3	Q1(e,f) Q2(b)Q5(a,b,c)Q6(b,c)	33